



# SBR/SKBPC35005 THRU SBR/SKBPC3510

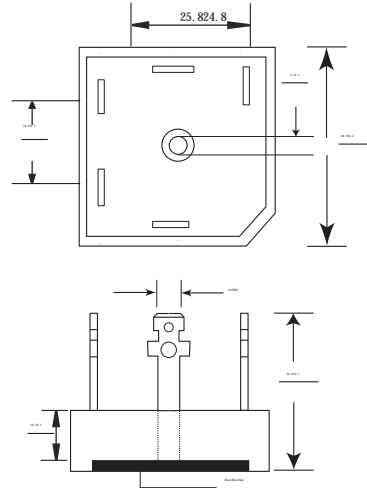
Voltage Range  
-50 to 1000 Volts  
Current  
-35.0 Ampere

### Features

- Diffused Junction
- Low forward voltage drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Boards

### MECHANICAL DATA

Case: Epoxy Case with Heat Sink Internally  
MIL-STD-202, Method 208  
Polarity: As Marked on Body  
Weight: 20 grams (approx)  
Mounting Position  
Bolt Down on Heatsink With Silicone Thermal Compound Between Bright and Mounting Surface for Maximum Heat Transfer Efficiency  
Mounting Torque: 20 in lbs. Max.  
Marking: Type Number



### Maximum Ratings and Electrical Characteristics

Rating at AC ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

### VOLTAGE RATINGS

CHARACTERISTICS	SYMBOL	-00	-01	-02	-04	-06	-08	-10	-12	-14	-16	UNT
Peak Repetitive Reverse Voltage Working Peak Reverse voltage DC Blocking Voltage	VRRM VR WM VR	50	100	200	400	600	800	1000	1200	1400	1600	V
Peak Non-Repetitive Reverse Voltage	VRSM	75	150	275	500	725	900	1100	1300	1500	1700	V
PMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	840	980	1120	V

### FOR WARD CONDUCTION

CHARACTERISTICS	SYMBOL	MT35	UNIT
Maximum Average Forward Rectified Current @ Tc=100°C	IO	35	A
Non-Repetitive Peak Forward Surge Current (No voltage Reapplied t=8.3ms at 60Hz) (No voltage Reapplied t=10ms at 50Hz) (100% VRRM Reapplied t=8.3ms at 60Hz) (100% VRRM Reapplied t=10ms at 50Hz)	IFMS	500 475 420 400	A
I2t Rating for fusing (No voltage Reapplied t=8.3ms at 60Hz) (No voltage Reapplied t=10ms at 50Hz) (100% VRRM Reapplied t=8.3ms at 60Hz) (100% VRRM Reapplied t=10ms at 50Hz)	I2t	1030 130 730 800	A2S
Forward Voltage (per element) @TJ=25°C, @LFM=40APK per single junction	VF	1.19	V
Peak Reverse Current (per leg) @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR	10 5.0	uA mA
RMS Isolation Voltage from Case to Lead	Vlso	2500	V

### THERMAL CHARACTERISTICS

Operating T. emperature Range	TJ	-40 to +150	°C
Storage T. emperature Range	TSTG	-40 to +150	°C
Thermal Resistance Junction to Case at DC Operation per Bridge	RQ JC	1.16	K/W
Thermal Resistance Case to Case to Heatsink Mounting Surface, Smooth, Flat and Greased	RQ CS	0.2	K/W